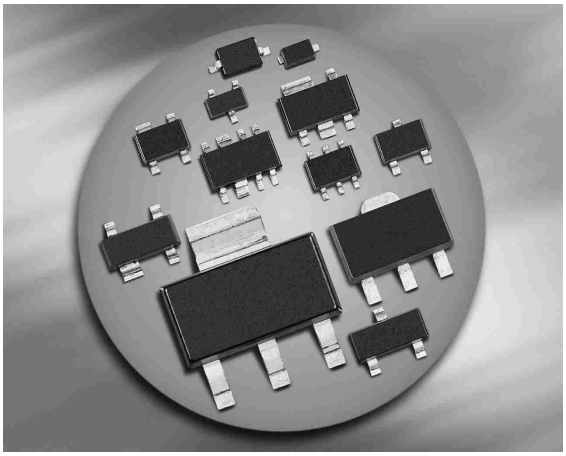
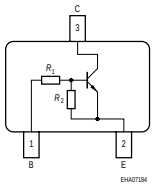
NPN Silicon Digital Transistor

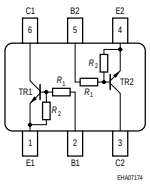


- Switching circuit, inverter, interface circuit, driver circuit
- Built in bias resistor (R_1=22kΩ, R_2=22kΩ)
- BCR141S : Two internally isolated transistors with good matching in one multichip package
- BCR141S: For orientation in reel see package information below
- Pb-free (RoHS compliant) package
- Qualified according AEC Q101

AEC Qualified RoHS

BCR141 **BCR141S**
BCR141W





Type	Marking	Pin Configuration						Package
BCR141	WDs	1=B	2=E	3=C	-	-	-	SOT23
BCR141S	WDs	1=E1	2=B1	3=C2	4=E2	5=B2	6=C1	SOT363
BCR141W	WDs	1=B	2=E	3=C	-	-	-	SOT323

Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-emitter voltage	V_{CEO}	50	V
Collector-base voltage	V_{CBO}	50	
Input forward voltage	$V_{i(fwd)}$	60	
Input reverse voltage	$V_{i(rev)}$	10	
Collector current	I_C	100	mA
Total power dissipation-	P_{tot}		mW
BCR141, $T_S \leq 118°C$		250	
BCR141S, $T_S \leq 115°C$		250	
BCR141W, $T_S \leq 124°C$		250	
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-65 ... 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point[1)]	R_{thJS}		K/W
BCR141		≤ 130	
BCR141S		≤ 90	
BCR141W		≤ 140	

[1]For calculation of R_{thJA} please refer to Application Note AN077 (Thermal Resistance Calculation)

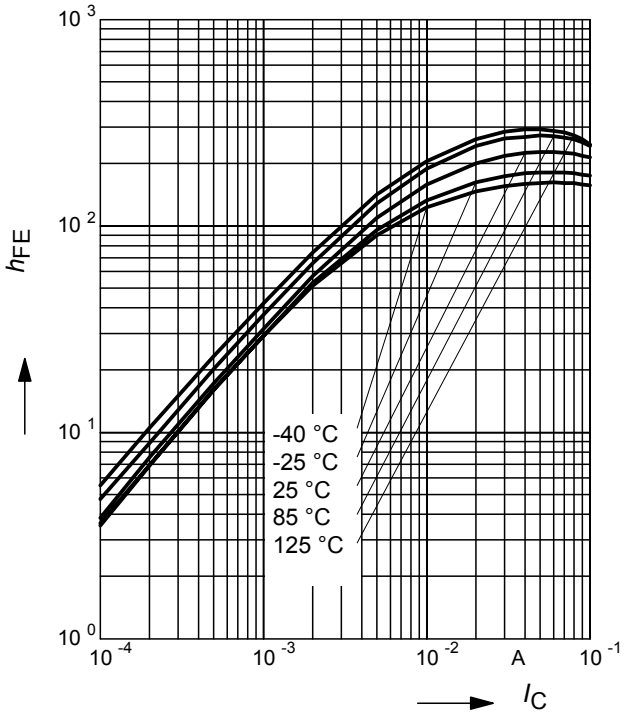
Electrical Characteristics at T_A = 25°C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Collector-emitter breakdown voltage I_C = 100 µA, I_B = 0	$V_{(BR)CEO}$	50	-	-	V
Collector-base breakdown voltage I_C = 10 µA, I_E = 0	$V_{(BR)CBO}$	50	-	-	
Collector-base cutoff current V_{CB} = 40 V, I_E = 0	I_{CBO}	-	-	100	nA
Emitter-base cutoff current V_{EB} = 10 V, I_C = 0	I_{EBO}	-	-	350	µA
DC current gain[1)] I_C = 5 mA, V_{CE} = 5 V	h_{FE}	50	-	-	-
Collector-emitter saturation voltage[1)] I_C = 10 mA, I_B = 0.5 mA	V_{CEsat}	-	-	0.3	V
Input off voltage I_C = 100 µA, V_{CE} = 5 V	$V_{i(off)}$	0.8	-	1.5	
Input on voltage I_C = 2 mA, V_{CE} = 0.3 V	$V_{i(on)}$	1	-	2.5	
Input resistor	R_1	15	22	29	kΩ
Resistor ratio	R_1/R_2	0.9	1	1.1	-
AC Characteristics					
Transition frequency I_C = 10 mA, V_{CE} = 5 V, f = 100 MHz	f_T	-	130	-	MHz
Collector-base capacitance V_{CB} = 10 V, f = 1 MHz	C_{cb}	-	3	-	pF

[1]Pulse test: t < 300µs; D < 2%

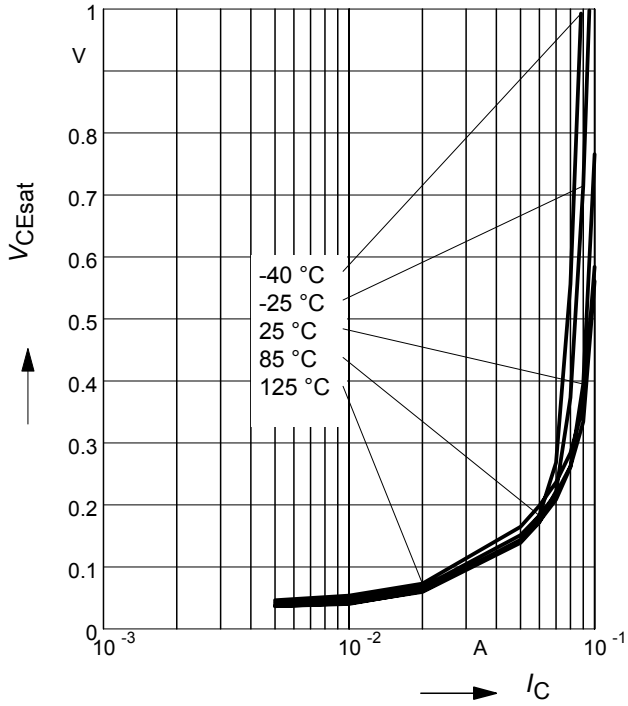
DC current gain $h_{FE} = f(I_C)$

V_{CE} = 5 V (common emitter configuration)



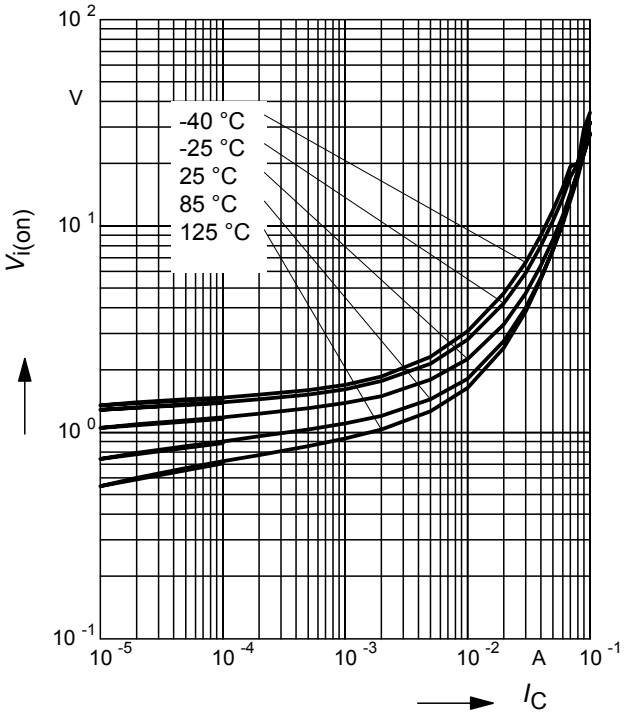
Collector-emitter saturation voltage

$V_{CEsat} = f(I_C)$, I_C/I_B = 20



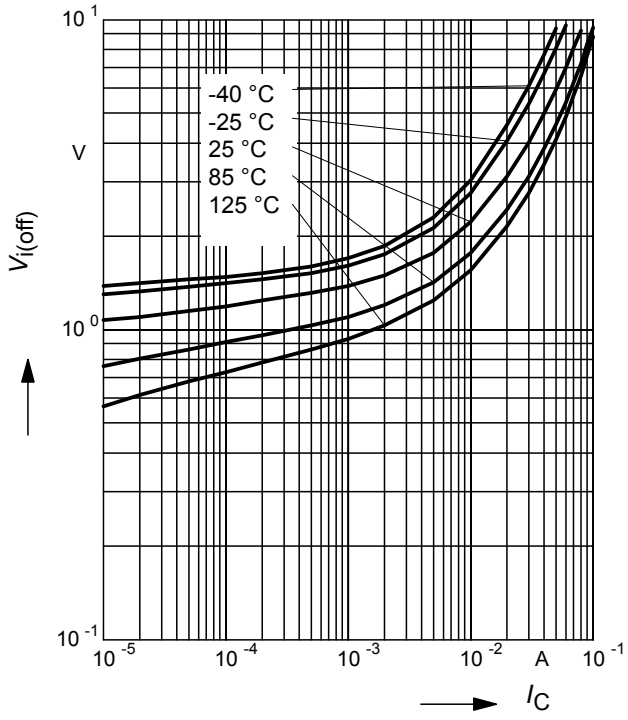
Input on Voltage $V_{i(on)} = f(I_C)$

V_{CE} = 0.3V (common emitter voltage)

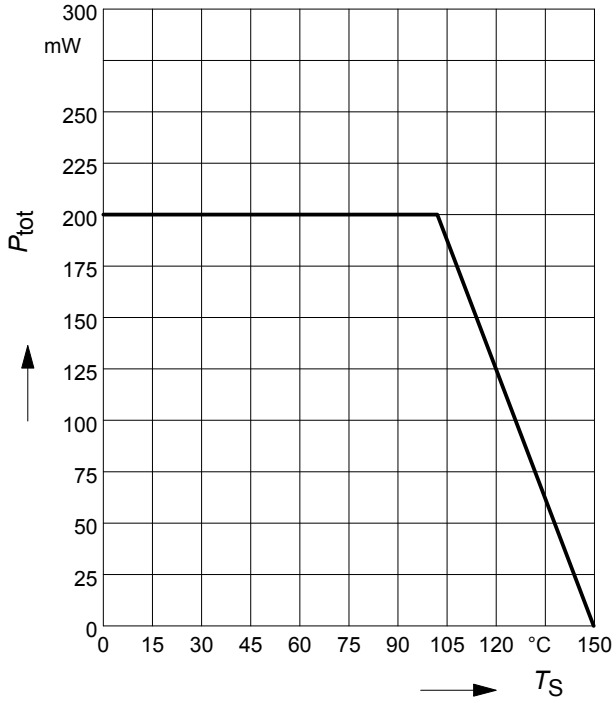


Input off voltage $V_{i(off)} = f(I_C)$

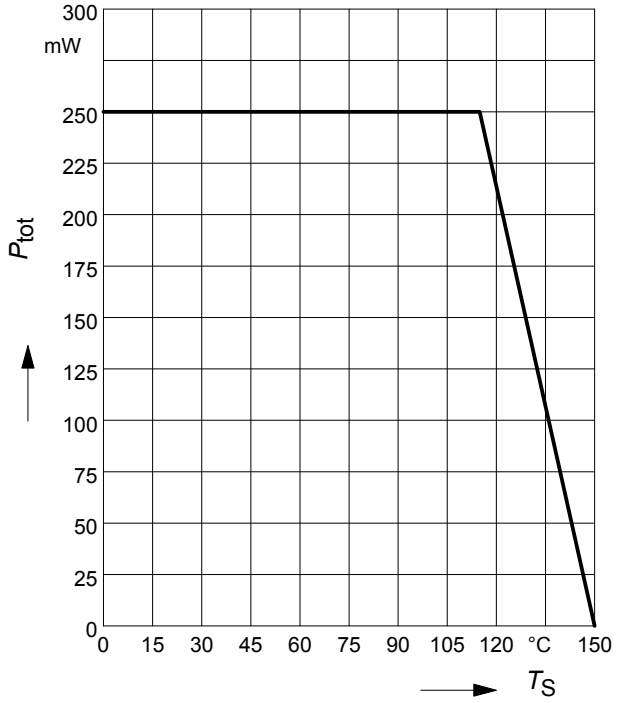
V_{CE} = 5V (common emitter voltage)



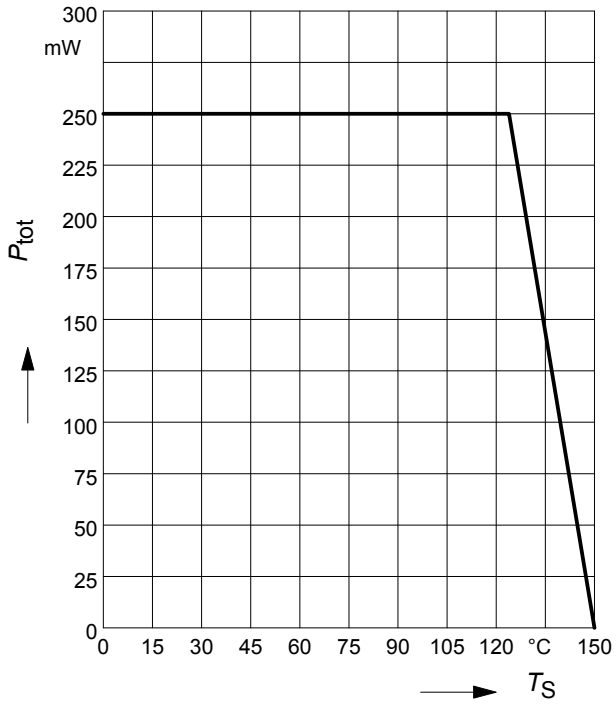
Total power dissipation $P_{tot} = f(T_S)$
BCR141



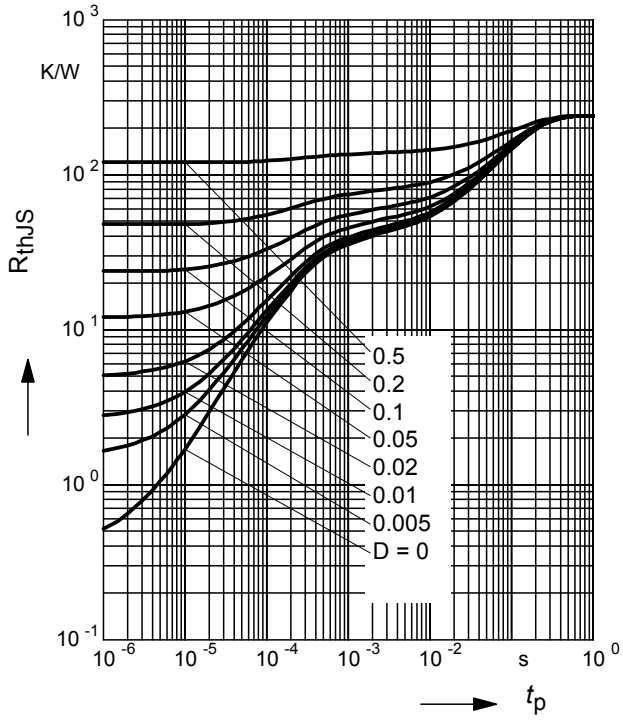
Total power dissipation $P_{tot} = f(T_S)$
BCR141S



Total power dissipation $P_{tot} = f(T_S)$
BCR141W



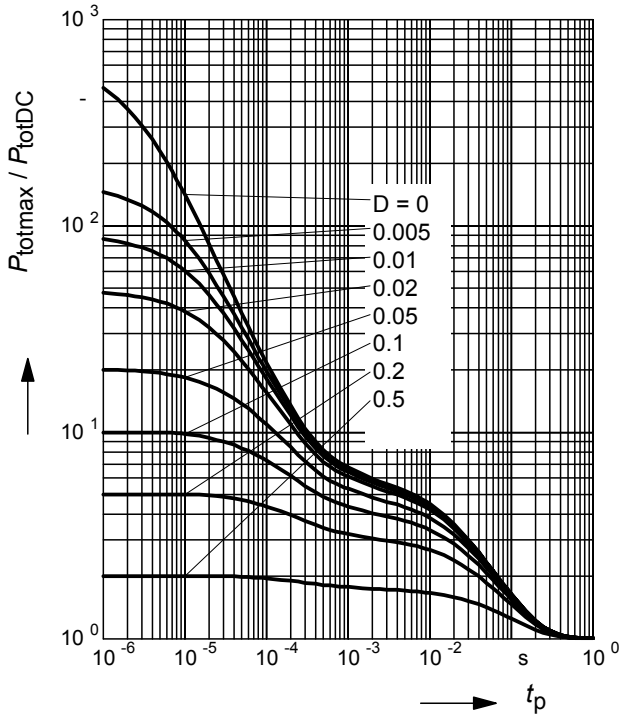
Permissible Pulse Load $R_{thJS} = f(t_p)$
BCR141



Permissible Pulse Load

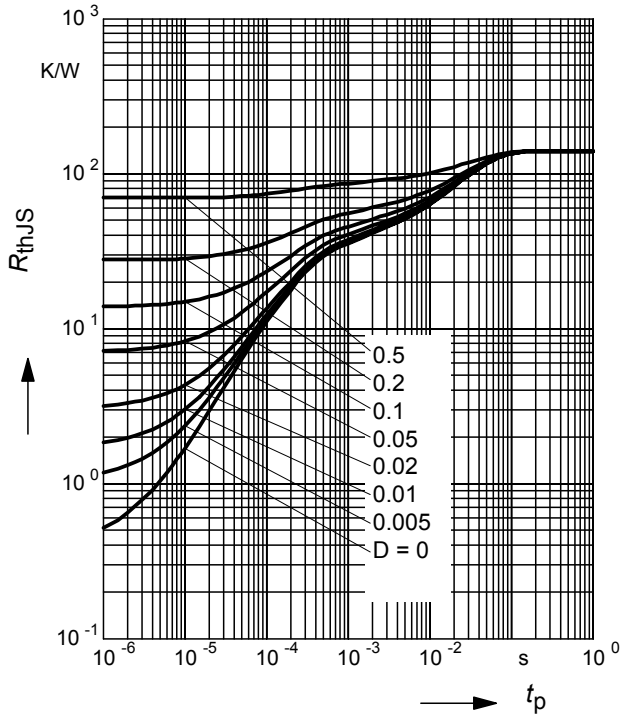
$P_{totmax}/P_{totDC} = f(t_p)$

BCR141



Permissible Puls Load $R_{thJS} = f(t_p)$

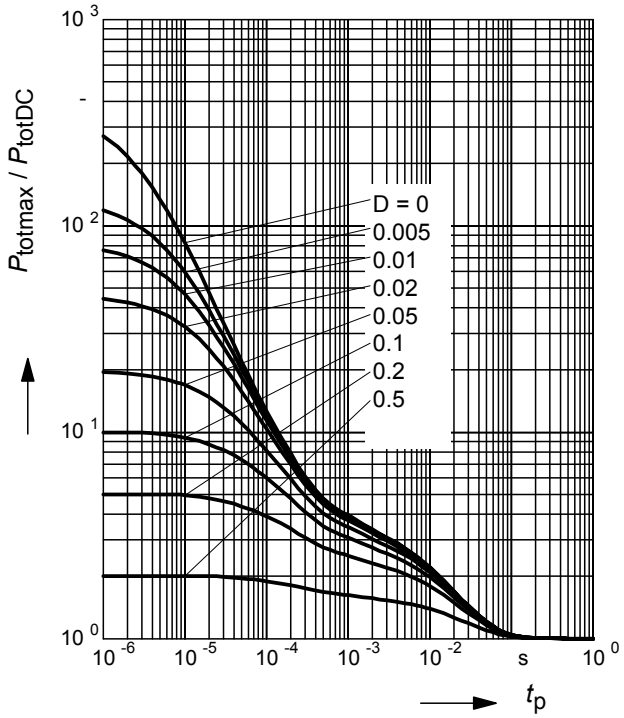
BCR141S



Permissible Pulse Load

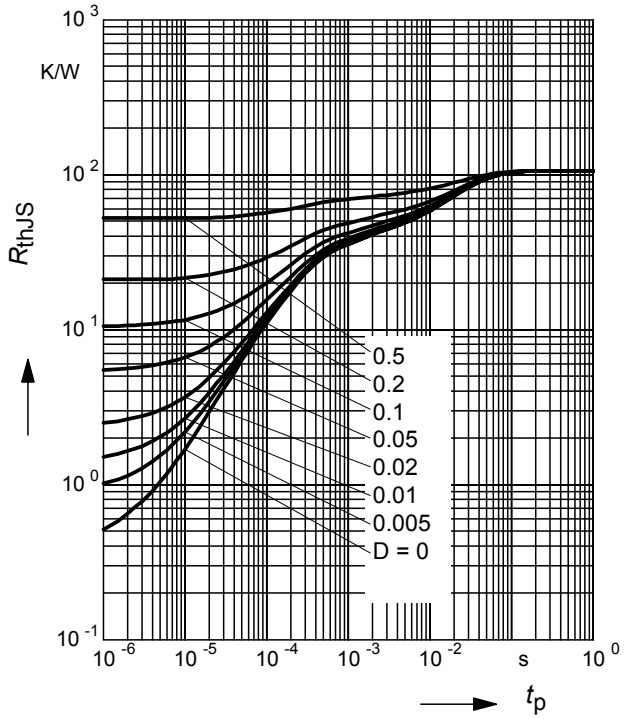
$P_{totmax}/P_{totDC} = f(t_p)$

BCR141S



Permissible Puls Load $R_{thJS} = f(t_p)$

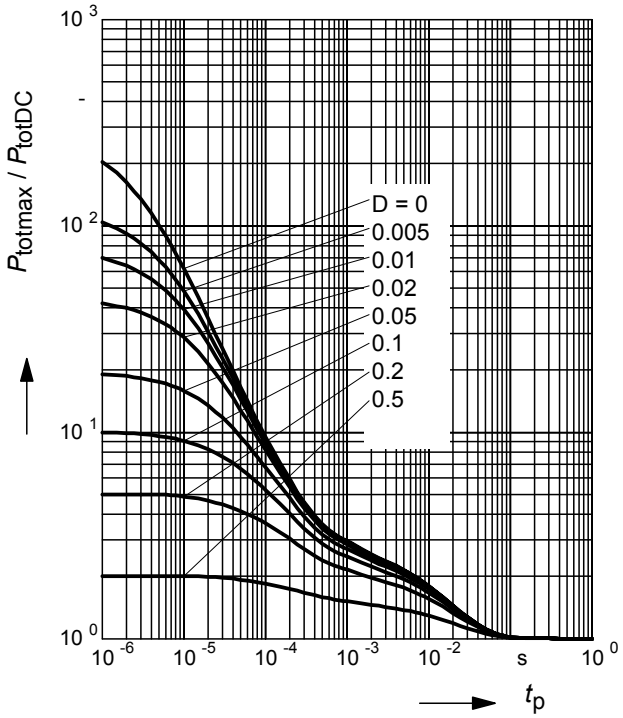
BCR141W



Permissible Pulse Load

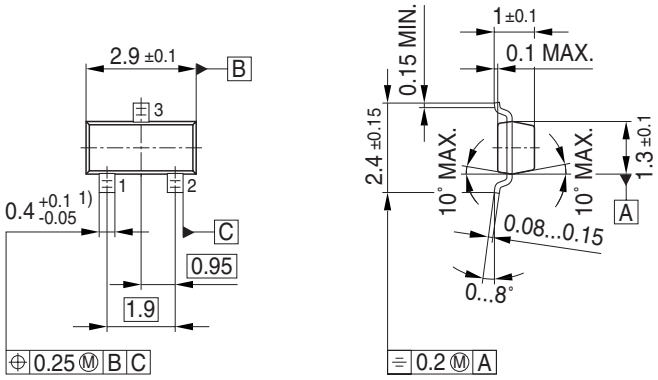
$P_{totmax}/P_{totDC} = f(t_p)$

BCR141W



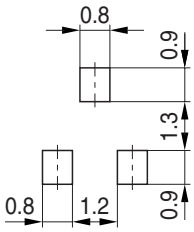
Package Outline



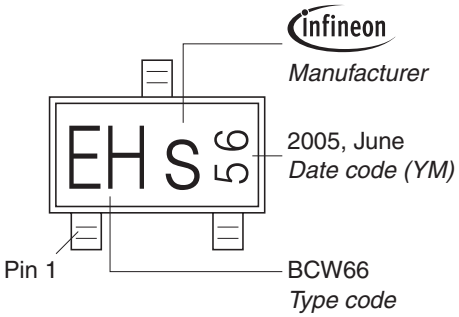


1) Lead width can be 0.6 max. in dambar area

Foot Print

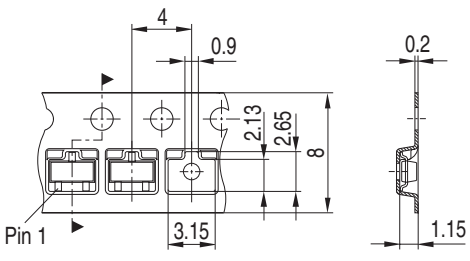


Marking Layout (Example)



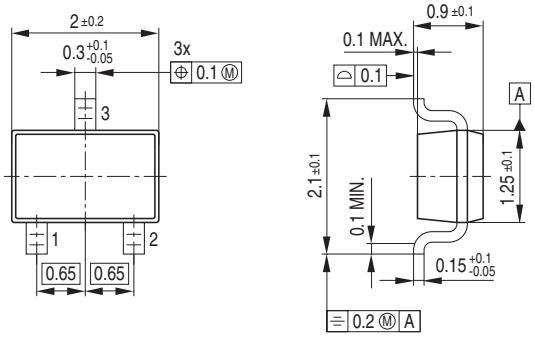
Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel
Reel ø330 mm = 10.000 Pieces/Reel

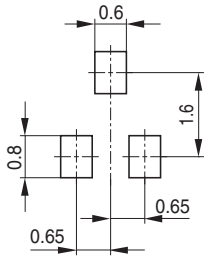


Package Outline

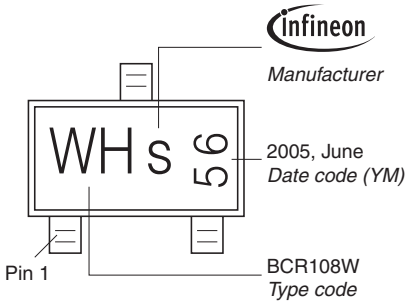




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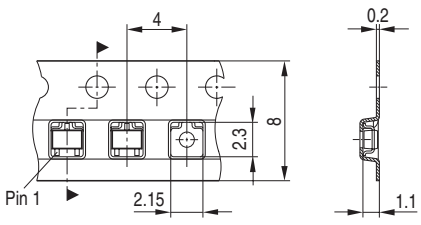


Marking Layout (Example)

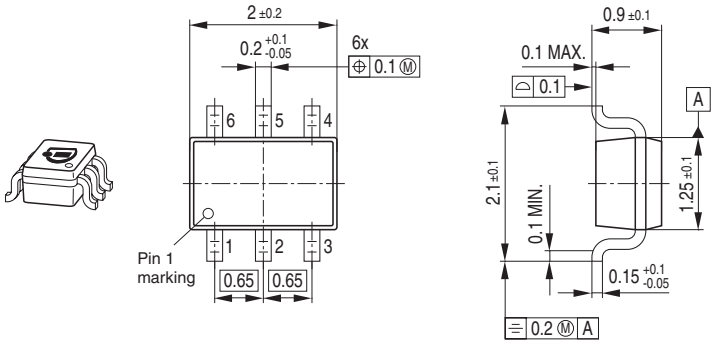


Standard Packing

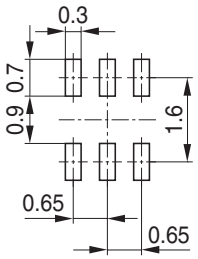
Reel ø180 mm = 3.000 Pieces/Reel
Reel ø330 mm = 10.000 Pieces/Reel



Package Outline

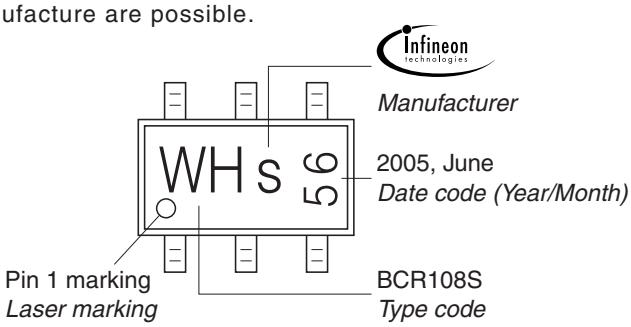


Foot Print



Marking Layout (Example)

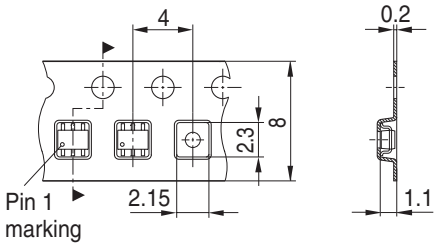
Small variations in positioning of
Date code, Type code and Manufacture are possible.



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel
Reel ø330 mm = 10.000 Pieces/Reel

For symmetric types no defined Pin 1 orientation in reel.



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